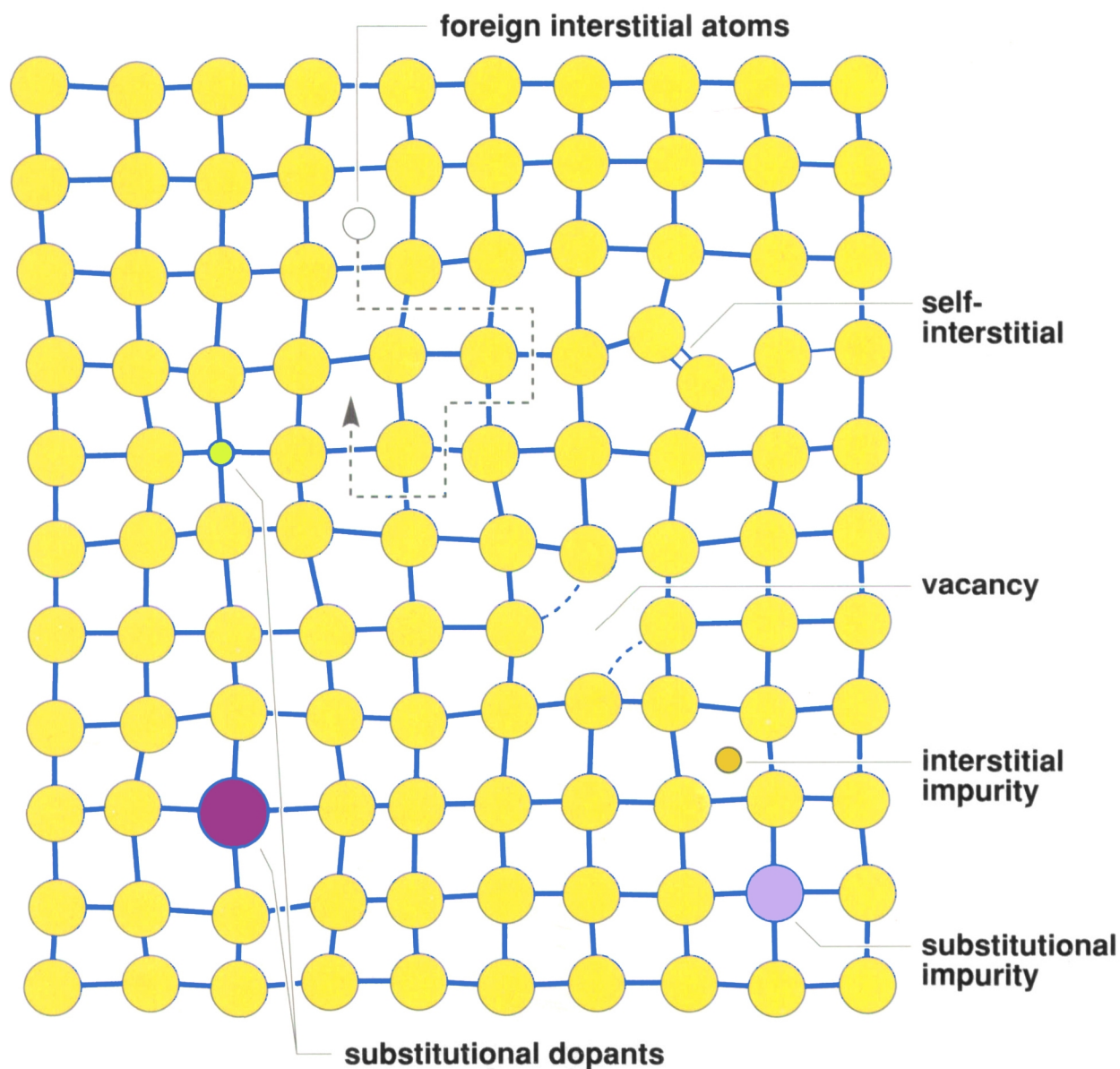




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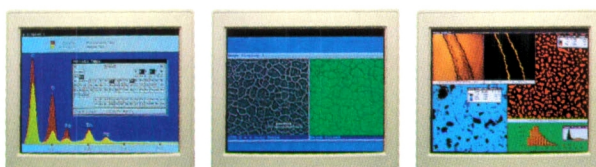
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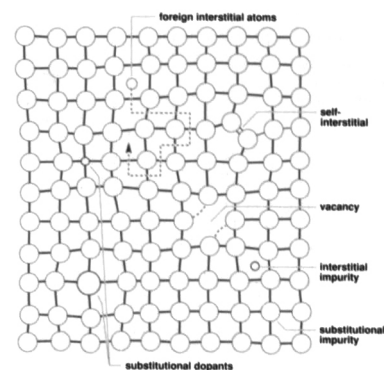
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ON THE COVER: Schematic, two-dimensional representation shows various types of intrinsic and extrinsic point defects that could be present in an elemental semiconductor crystal such as silicon. For more information on this topic, see "Point Defects and Diffusion in Semiconductors" by U.M. Gösele and T.Y. Tan on p. 42.

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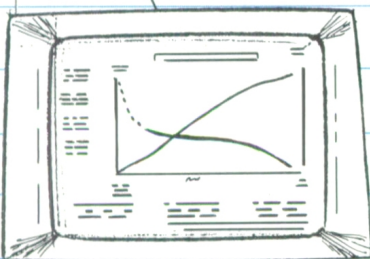
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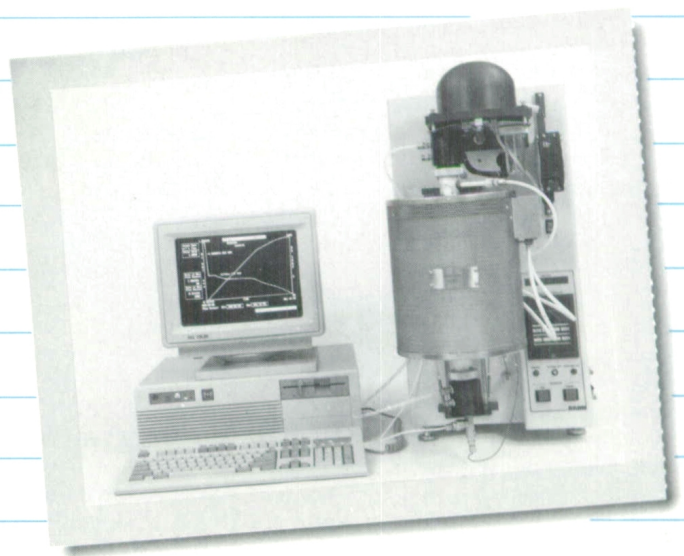
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